Vishay High Power Products

ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 200 A

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL pending
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- · High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

The VSKDS403.. Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	200	А		
V _{RRM}		100	V		
I _{FSM}	t _p = 5 μs sine	25 500	А		
V _F	100 Apk, T _J = 125 °C	0.66	V		
TJ	Range	- 55 to 175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VSKDS403/100	UNITS		
Maximum DC reverse voltage	V _R	100	V		
Maximum working peak reverse voltage	V _{RWM}				





MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.



COMPLIANT

www.vishay.com



VSKDS403/100

Vishay High Power Products

ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 200 A



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 111 °C, rectangular waveform		200	
Maximum peak one cycle	Irou	5 µs sine or 3 µs rect. pulse Following any rated	Following any rated load condition and with	25 500	А
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	3300	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 5.5 \text{ A}, L = 1 \text{ mH}$		15	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		200 A	T ₁ = 25 °C	0.99	- V
Maximum forward voltage drop	V	400 A	1,3 IIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIII	1.3	
Maximum forward voltage drop	V _{FM}	200 A	T - 105 °C	0.83	
		400 A	T _J = 125 °C	1.09	
		T _J = 25 °C	V _R = Rated V _R	6	mA
Maximum reverse leakage current	I _{RM}	T _J = 125 °C		80	
Maximum junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		55 000	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg	B _{thic} DC operation 0.2		0.26	°C/W	
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	
Approvimete weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
	busbar		spread of the compound.	3	NIII
Case style			JEDEC	TO-240AA co	ompatible



1000

100

10

1

VSKDS403/100

ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 200 A

Tj = 175°C

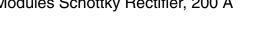
Tj = 25°C

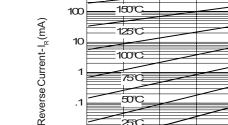
 $0.0 \quad 0.2 \quad 0.4 \quad 0.6 \quad 0.8 \quad 1.0 \quad 1.2 \quad 1.4 \quad 1.6$

Forward Voltage $Drop-V_{FM}(V)$

Fig. 1 - Maximum Forward Voltage Drop Characteristics

Vishay High Power Products





=175°C

1000

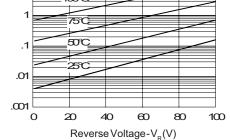
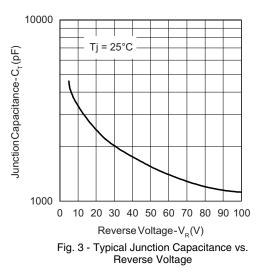
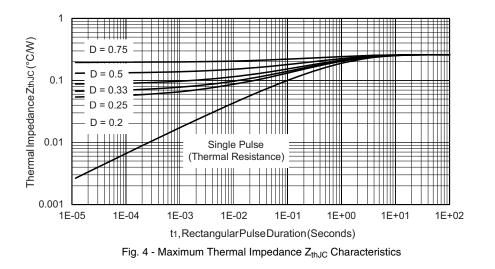
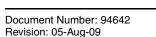


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





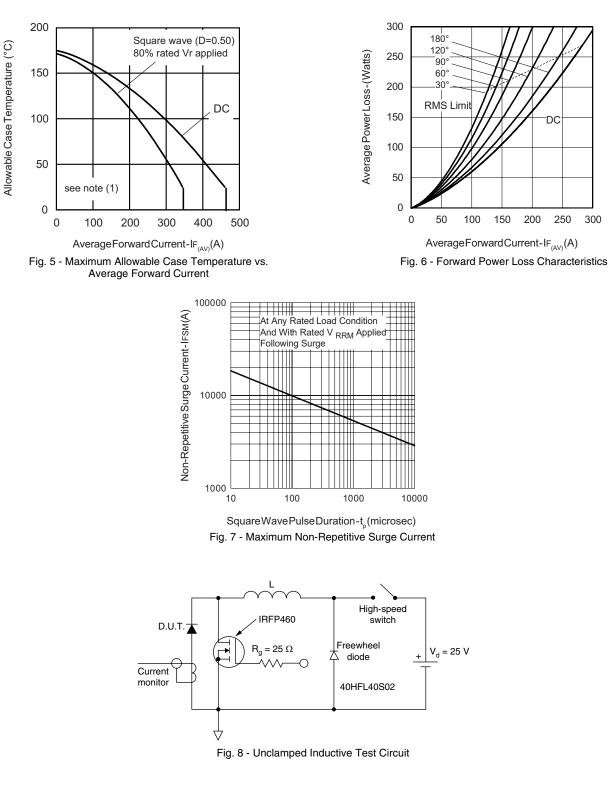
nstantaneous Forward Current-I $_{\mathsf{F}}(\mathsf{A})$

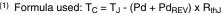


VSKDS403/100

Vishay High Power Products

ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 200 A





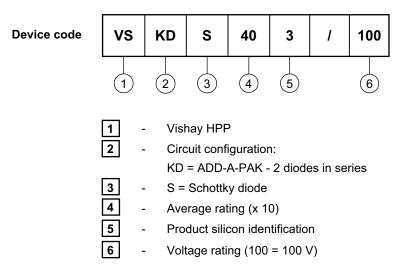
⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = 80 \% rated V_R$

Note

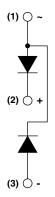


ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 200 A Vishay High Power Products

ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

Vishay Semiconductors



ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.